



# Understanding of radiation effects and damage in nuclear reactors materials using JANNuS ion beams

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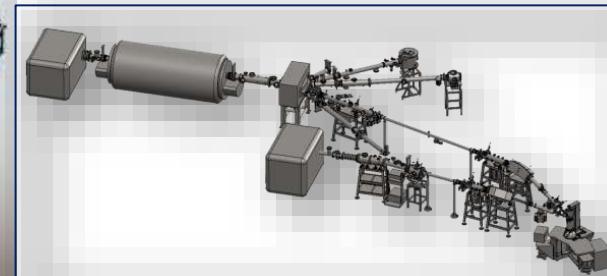
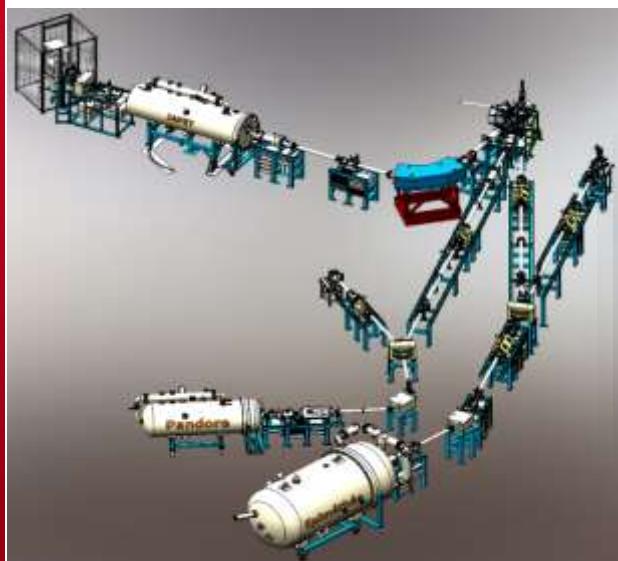


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## EUROMAT 2017 / Symposium D9

Thessaloniki, Greece, September 17-22, 2017

**Understanding radiation effects and damages in nuclear reactor materials using JANNuS ion beams**



**Céline Cabet, Aurélie Gentils,  
Université Paris-Saclay, France**

# JANNuS: 1 platform, 2 facilities

**Joint Accelerators for Nanoscience and Nuclear Simulation**

**GIS JANNuS (scientific interest grouping since 2004)**

→ Founding partner of the French accelerator network



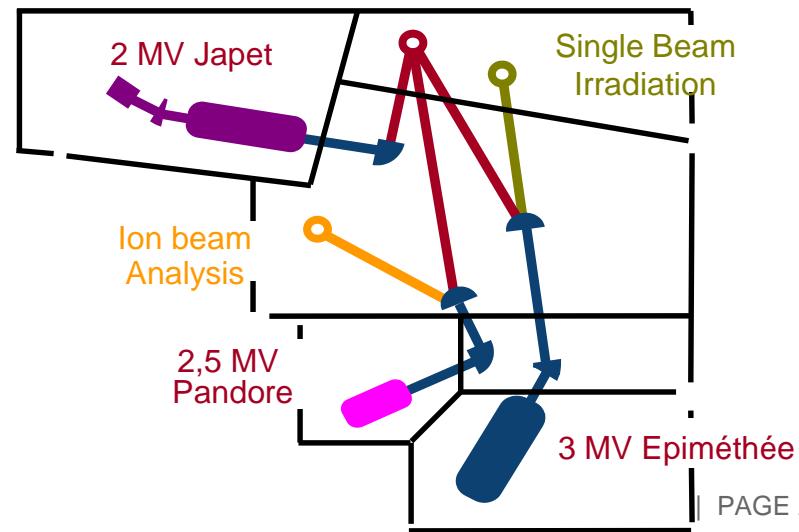
<http://emir.in2p3.fr>

→ Simulation of damage accumulation induced by neutrons in nuclear materials

**JANNuS Orsay**  
on line TEM coupled  
to one or two beams



**JANNuS Saclay**  
triple beam irradiation facility with  
high damage rate



# The *in situ* dual ion beam TEM at CSNSM : JANNuS-Orsay facility

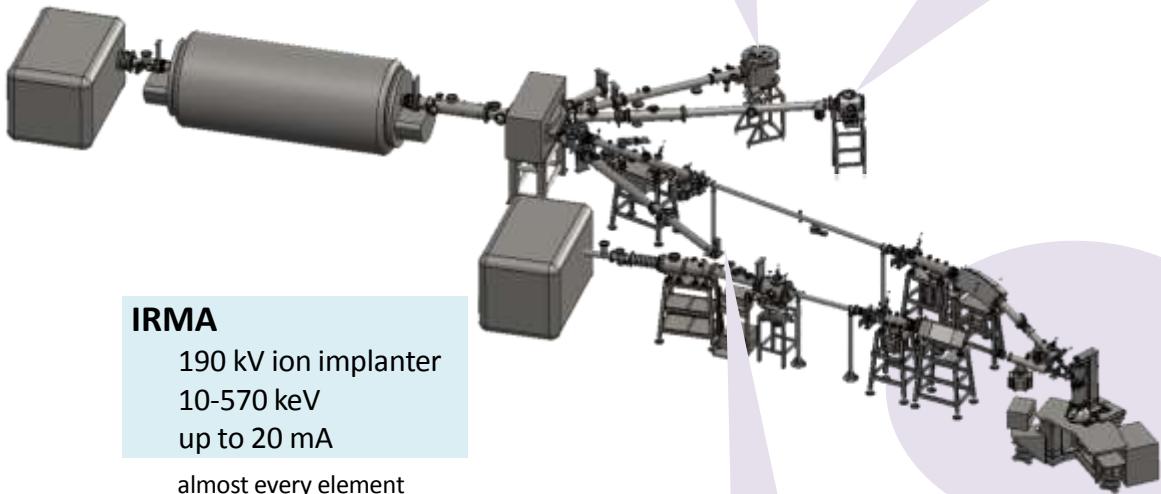
## ARAMIS

2MV Tandem - VdG  
 0.5 – 11 MeV \*  
 10 nA – 10  $\mu$ A

> 40 elements  
 \* limited to 1 MeV per charge state inside the TEM

**Ion Beam Analysis**  
 RBS, RBS/C, ERDA,  
 PIXE,  $\mu$ PIXE, PIGE

**implantation / irradiation**  
 $\text{LN}_2 \rightarrow 1000^\circ\text{C}$



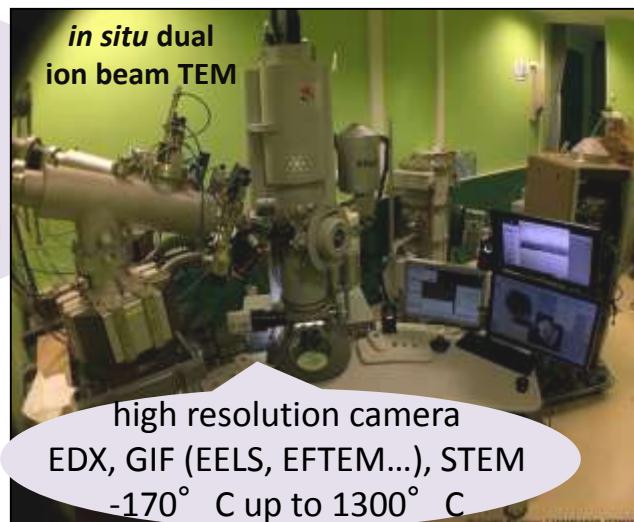
## IRMA

190 kV ion implanter  
 10-570 keV  
 up to 20 mA

almost every element

*in situ* RBS/C  
 and implantation  
 $\text{LN}_2 \rightarrow 600^\circ\text{C}$

**TRANSMISSION ELECTRON MICROSCOPE**  
 200 kV FEI Tecnai G2 F20 Twin  
 Resolution: 0.25 nm  
 Magnification range: 70-700 000



**high resolution camera**  
 EDX, GIF (EELS, EFTEM...), STEM  
 $-170^\circ\text{ C}$  up to  $1300^\circ\text{ C}$

# ARAMIS ion accelerator

2MV Tandem – VdG

**HOME BUILT IN 1987**

## VAN DE GRAAFF MODE

Mainly H, He (also noble gaz)

200 keV – 1.8 MeV (H), 3.6 MeV (He)

Positive Penning ion source

> 20  $\mu$ A

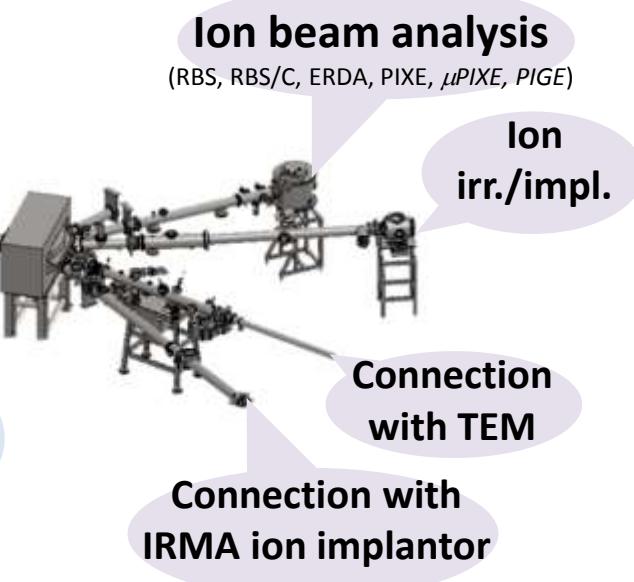
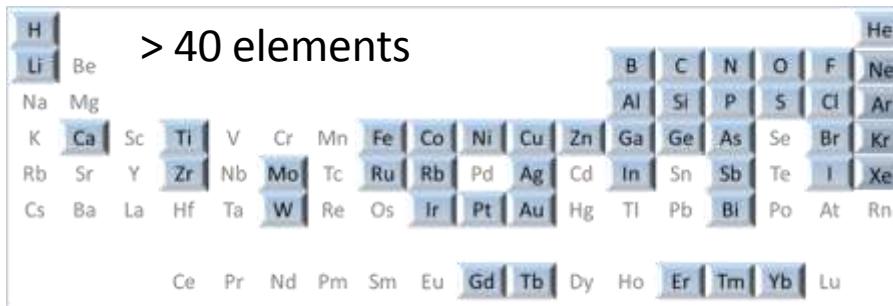


## TANDEM MODE

0.5-11\* MeV, 10 nA – 10 $\mu$ A

SNICS source (Source of Negative Ions by Cesium Sputtering)

\* limited to 1 MeV per charge state inside the TEM

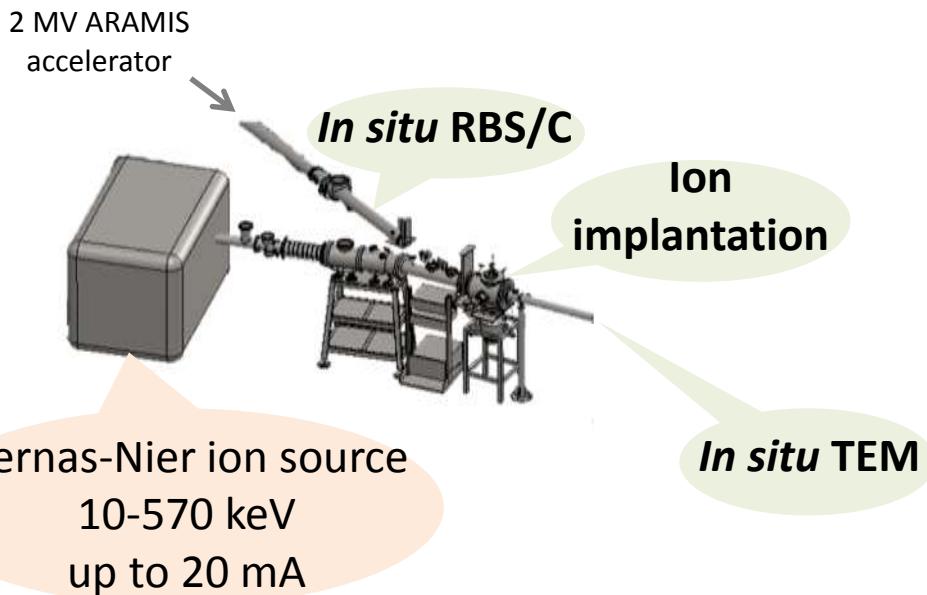
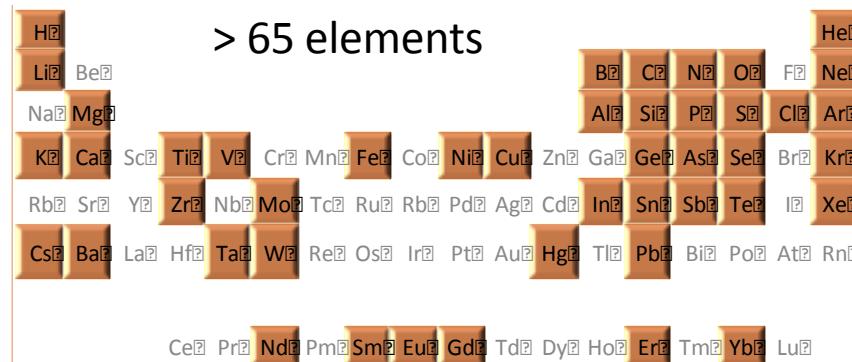


Typical irradiation conditions:

- Rastered beam  
(80 Hz vertical and 400 Hz horizontal)
- Average flux range  
 $1.10^{10} – 5.10^{11} \text{ cm}^{-2}.\text{s}^{-1}$   
(depending on ions and energies)
- Temperature  $\text{LN}_2 \rightarrow 1000^\circ\text{C}$   
(thermocouple control)

# IRMA 190 kV ion implanter

**HOME BUILT IN 1979**



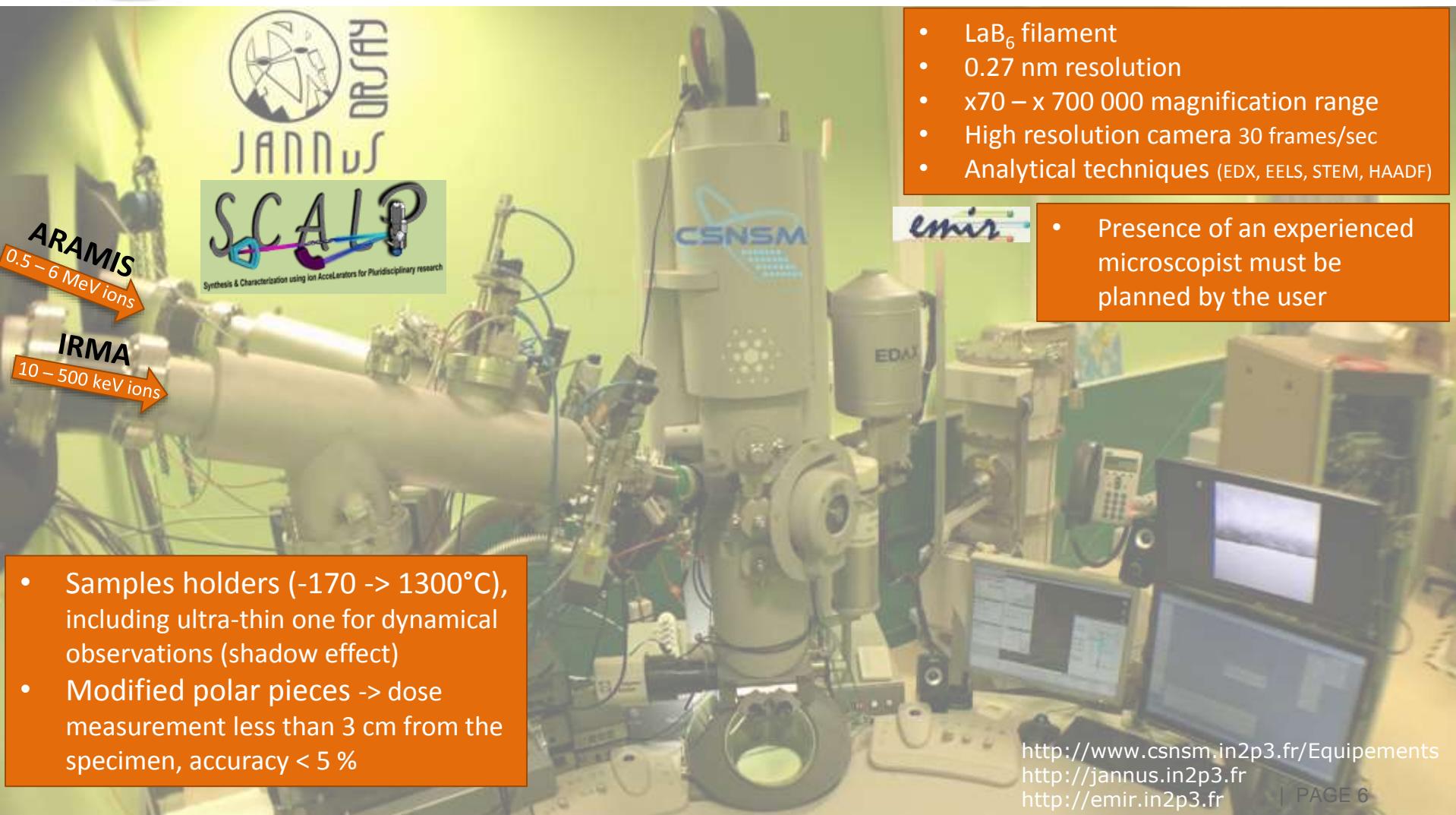
**Typical irradiation conditions:**

- Rastered beam  
(400 Hz vertical and 80 Hz horizontal)
- Average flux range  
 $1.10^{10} - 5.10^{12} \text{ cm}^{-2} \cdot \text{s}^{-1}$   
(depending on ions and energies)
- Temperature  $\text{LN}_2 \rightarrow 1000^\circ\text{C}$   
(thermocouple control)

# In situ dual ion beam Transmission Electron Microscope

1<sup>st</sup> TEM (120 kV EM400) connected to IRMA ion implanter in 1980

3<sup>rd</sup> TEM (200 kV FEI Tecnai G<sup>2</sup> F20 Twin, shown below) since 2009 for external users



# The *in situ* dual ion beam TEM at CSNSM : JANNuS-Orsay facility

## New and future developments

- **EDX update**

Chemical analysis => Brucker Flash 6 detector  
and Esprit software -> hyper-maps



- **New ultra-fast high resolution camera**

High quality image (4K)  
+ high-speed video capture (25 fps at 4K up to 300 fps at 512x512)  
+ ultra fast shutter = great tool for *in situ* imaging !

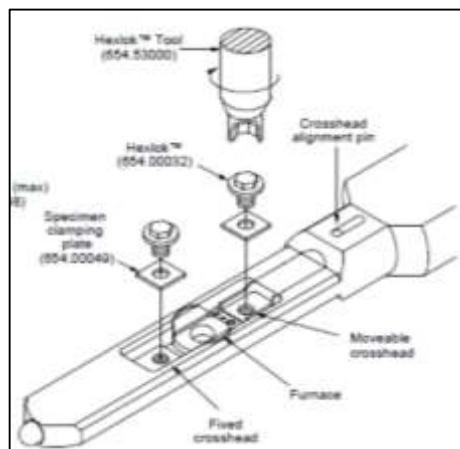


- **Environmental sample holder**

Liquid and/or gas under irradiation  
with heating control (+ options)



- **Straining heating holder (1000°C)**

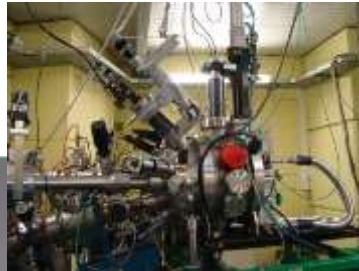


# JANNuS-Saclay: 3 complementary accelerators

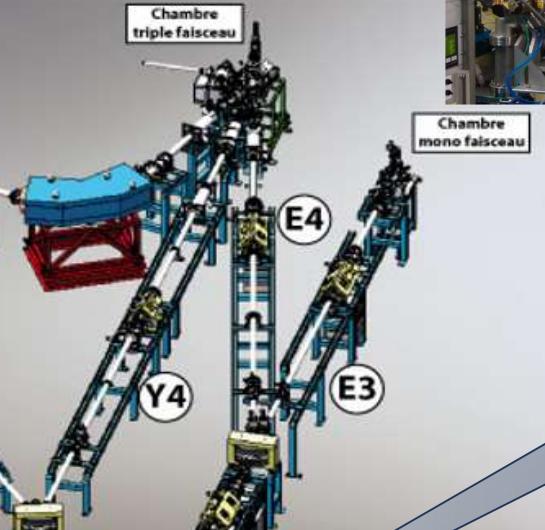
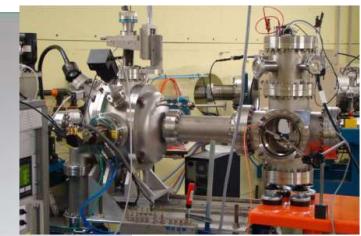
Heavy ion  
damage  
Hydrogen  
implantation



Japet  
Tandem 2 MV



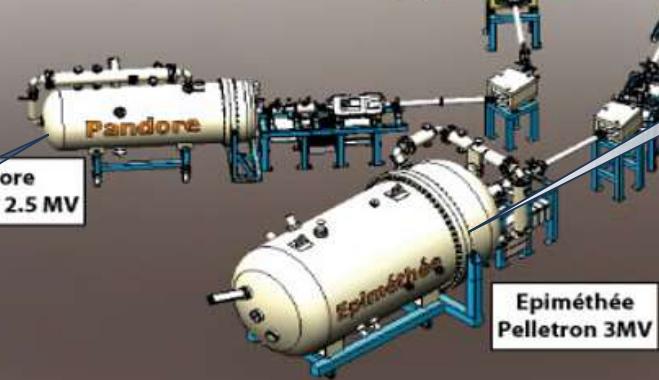
First triple beam irradiation  
in March 2010



Heavy ion damage  
Helium and  
hydrogen  
implantation



Pandore  
Pelletron 2.5 MV



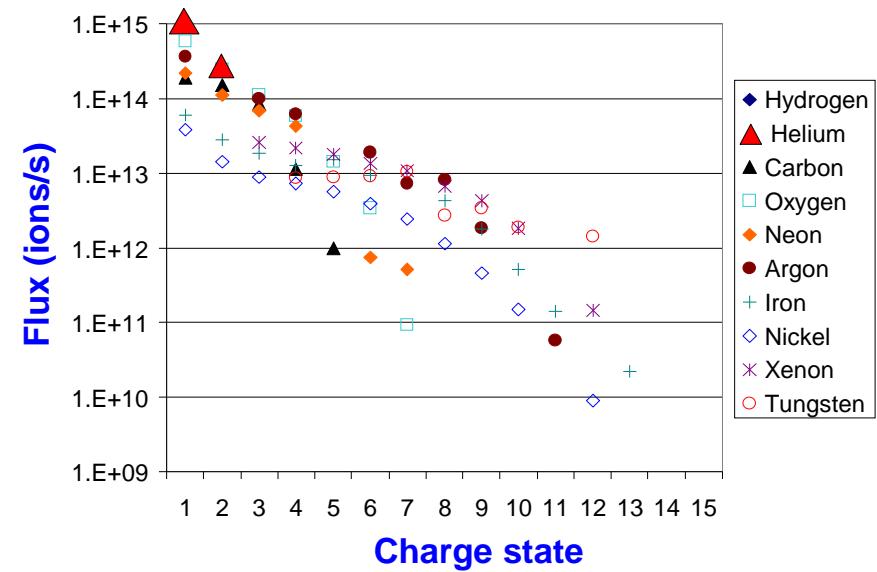
Helium and  
hydrogen  
implantation

Epiméthée  
Pelletron 3MV

- Accelerator: 3 MV Pelletron NEC (National Electrostatics Corporation) with a ECR (Electron Cyclotron Resonance) source from Pantechnik



⇒ Positive multi-charged ions  
 $1 < m < 209$   
 $400 \text{ keV} < E < 40 \text{ MeV}$



Ballistic damage with Fe (~10 dpa/h)

# JANNuS-SACLAY: 2 MV Tandem Japet and 2.5 MV Pelletron Pandore

**JAPET** 2 MV Tandem with Source of Negative Ions  
by Cesium Sputtering (SNICS II)



**PANDORE** 2.5 MV Pelletron with  
Radio Frequency source

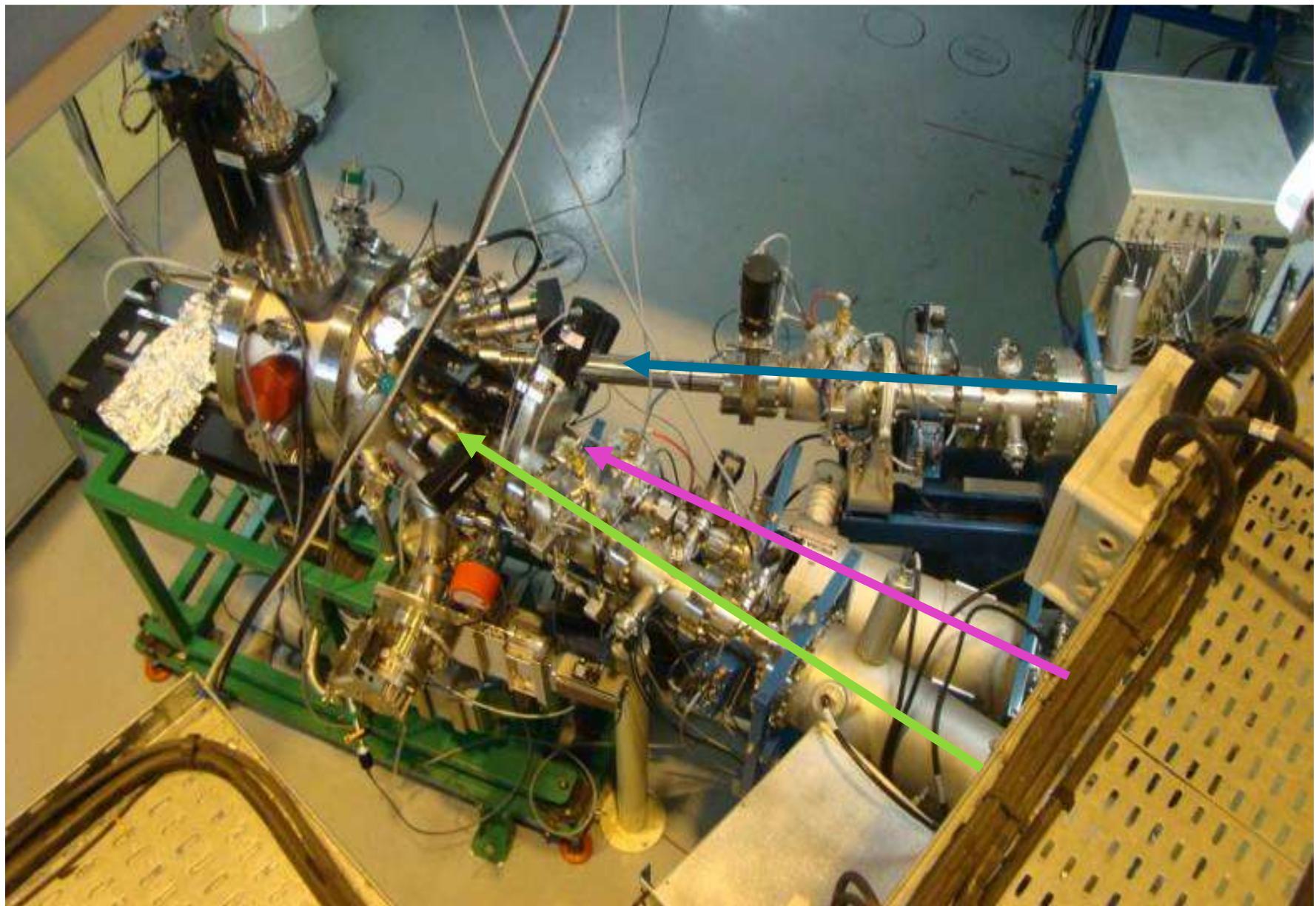


⇒ Negative single-charged ions are converted into positive multi-charged ions through the stripper

⇒ Single-charged gasses: H, He, D, N, Ar

	Epiméthée		Japet		Pandore												
	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18
H																	
Li	Li	Li	Be	Be													
Na	Na	Na	Mg	Mg													
K	K	K	Ca	Ca	Sc	Sc	Ti	Ti	V	V	Cr	Cr	Mn	Mn	Fe	Fe	
Rb	Rb	Rb	Sr	Sr	Y	Y	Zr	Zr	Nb	Nb	Mo	Mo	Tc	Tc	Ru	Ru	
Cs	Cs	Cs	Ba	Ba			Hf	Hf	Ta	Ta	W	W	Re	Re	Os	Os	
Fr	Fr	Fr	Ra	Ra													
					104	105	106	107	108	109	110	111	112	113	114	115	116
					Rf	Db	Sg	Bh	Hs	Mt	Ds	Rg					

# JANNuS-SACLAY: Irradiation chambers



## Complementary laser in the Raman spectrometer

- new laser with 633 nm in addition to the 532 nm

## Retrofit of the IBA chamber

- New detectors
- Specimen deck with 2 to 6 degrees of freedom allowing for canalization

## High temperature chamber

- Extension of the single beam chamber for irradiation at homogenous temperature up to 1200°C

## Cryogenic chamber with resistivity recovery measurement



- Cryogenic irradiation at 30K
- Controlled step by step annealing
- On line measurement of sample resistivity (defect population and mobility)

3D view - 3F chamber, E. Bordas



# Radiation stability of nano-oxides in ODS steels

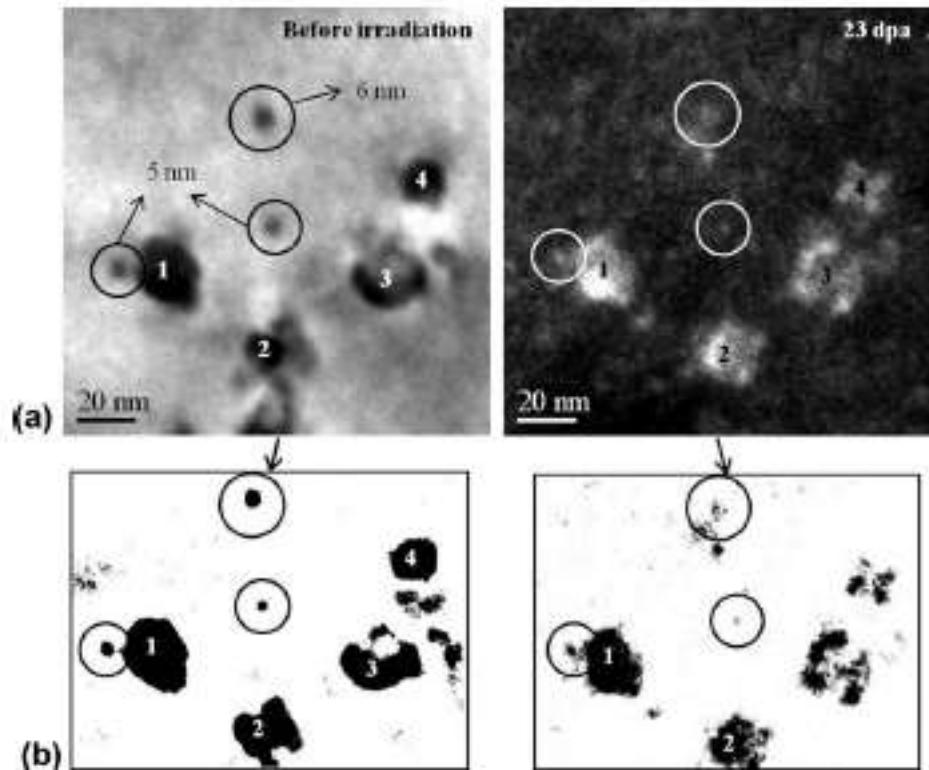


Example 1: M.-L. Lescoat, J. Ribis, Y. de Carlan et al.

## In situ TEM at JANNuS-Orsay

### Nano particle evolution

~23 dpa



Fe<sup>+</sup> 150 keV, 500°C  
φ 3.7 10<sup>12</sup> ion.cm<sup>-2</sup>.s<sup>-1</sup>  
Φ<sub>max</sub> 1.6 10<sup>12</sup> ion.cm<sup>-2</sup>.s<sup>-1</sup>  
(~45 dpa)

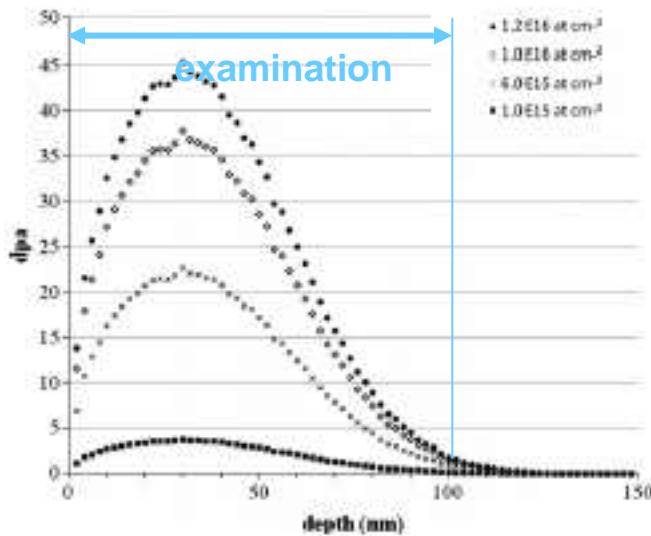


Fig. 1. Depth profiles of displacement damages in Fe calculated by SRIM.

# Radiation stability of nano-oxides in ODS steels

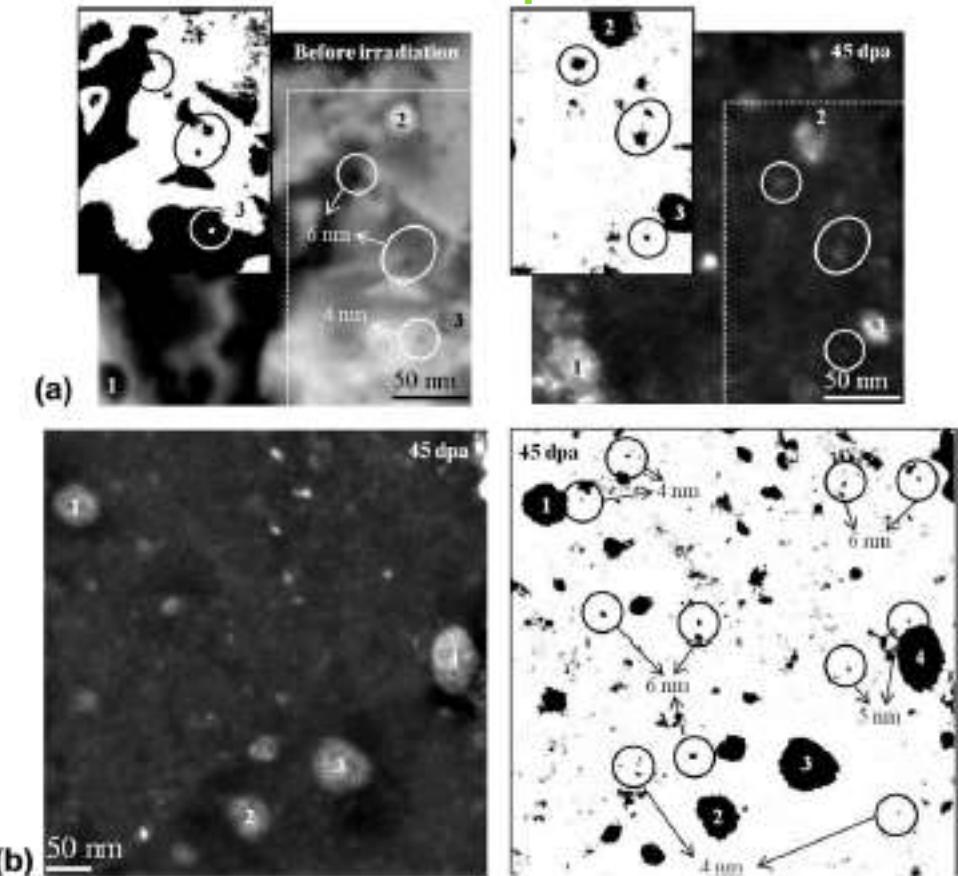


Example 1: M.-L. Lescoat, J. Ribis, Y. de Carlan et al.

## In situ TEM at JANNuS-Orsay

### Nano particle evolution

~45 dpa



Fe<sup>+</sup> 150 keV, 500°C  
 $\phi$   $3.7 \cdot 10^{12}$  ion.cm<sup>-2</sup>.s<sup>-1</sup>  
 $\Phi_{max}$   $1.6 \cdot 10^{16}$  ion.cm<sup>-2</sup>.s<sup>-1</sup>  
(~45 dpa)

Nanoparticles are still visible after irradiation at ~45 dpa

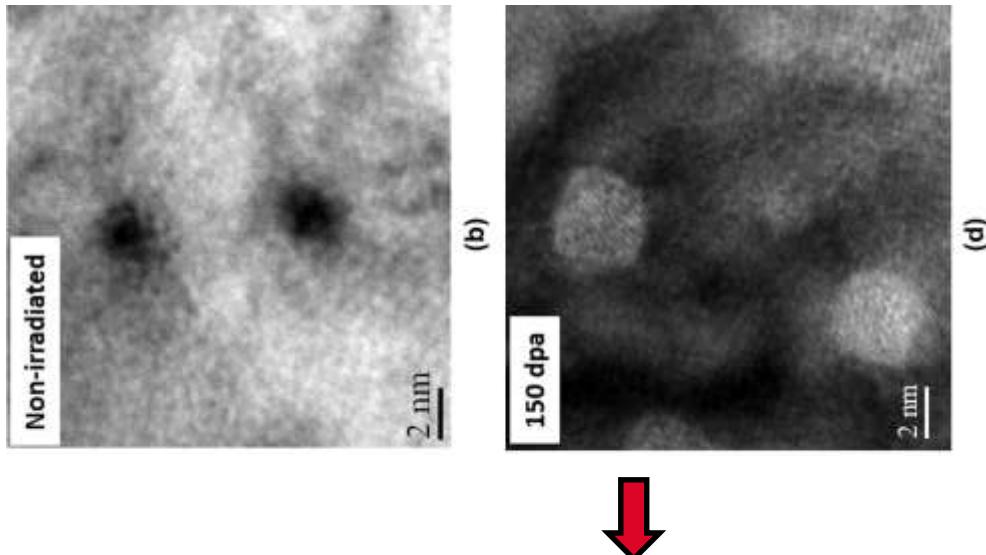
# Radiation stability of nano-oxides in ODS steels



Example 1: M.-L. Lescoat, J. Ribis, Y. de Carlan et al.

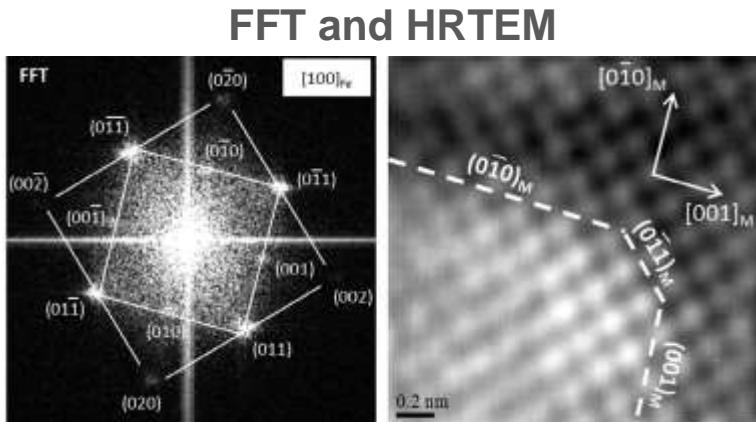
## High dose irradiation at JANNuS-Saclay

### Nanoparticle study

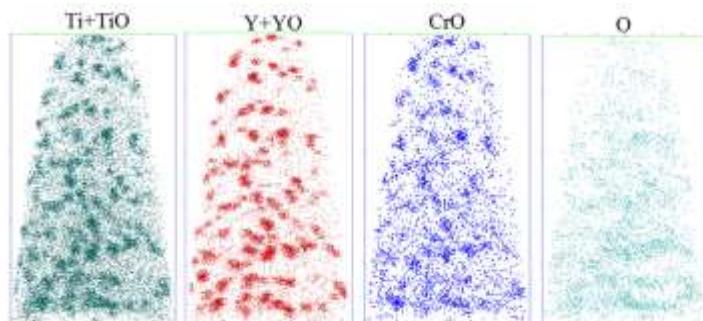


Nanoparticles are still dispersed after irradiation at high dose

Fe<sup>+</sup> 0.5 MeV, 500°C  
 $\phi 2.7 \cdot 10^{12} \text{ ion.cm}^{-2} \cdot \text{s}^{-1}$   
 $\Phi_{\max} 8.9 \cdot 10^{16} \text{ ion.cm}^{-2} \cdot \text{s}^{-1}$   
(~220 dpa)



### 3-D APT chemical reconstruction



# Radiation stability of nano-oxides in ODS steels

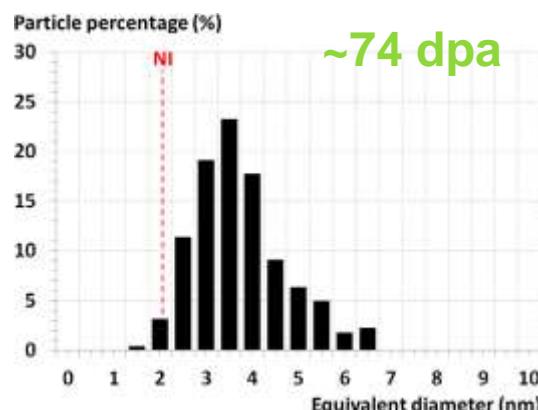
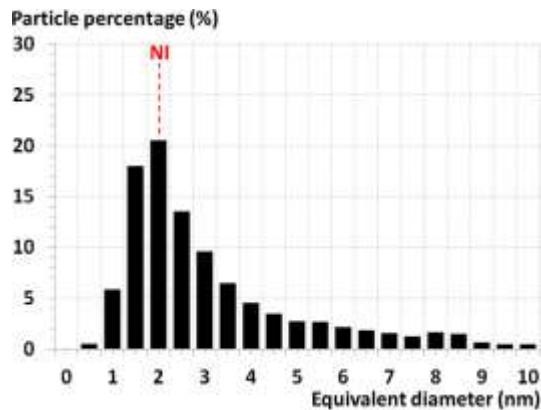
Example 1: M.-L. Lescoat, J. Ribis, Y. de Carlan et al.



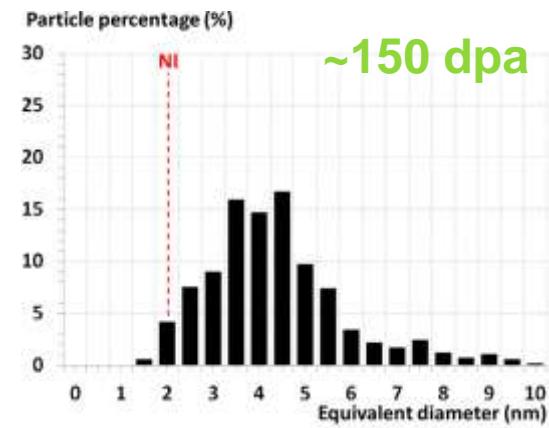
## High dose irradiation at JANNuS-Saclay

### Nanoparticle study

#### Statistics on nanoparticles distribution and size



Fe<sup>+</sup> 0.5 MeV, 500°C  
 $\phi 2.7 \cdot 10^{12} \text{ ion.cm}^{-2} \cdot \text{s}^{-1}$   
 $\Phi_{\max} 8.9 \cdot 10^{16} \text{ ion.cm}^{-2} \cdot \text{s}^{-1}$   
(~220 dpa)

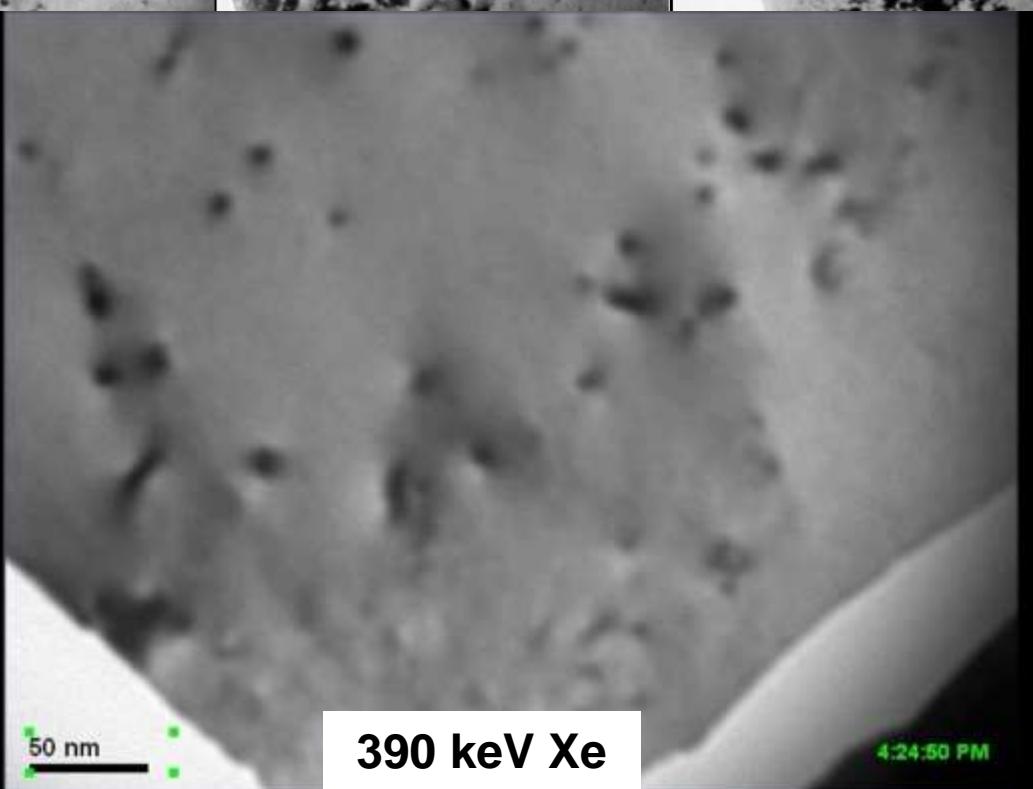
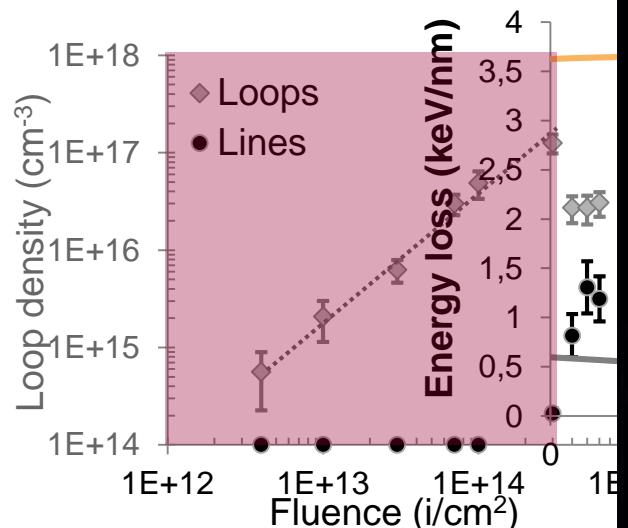
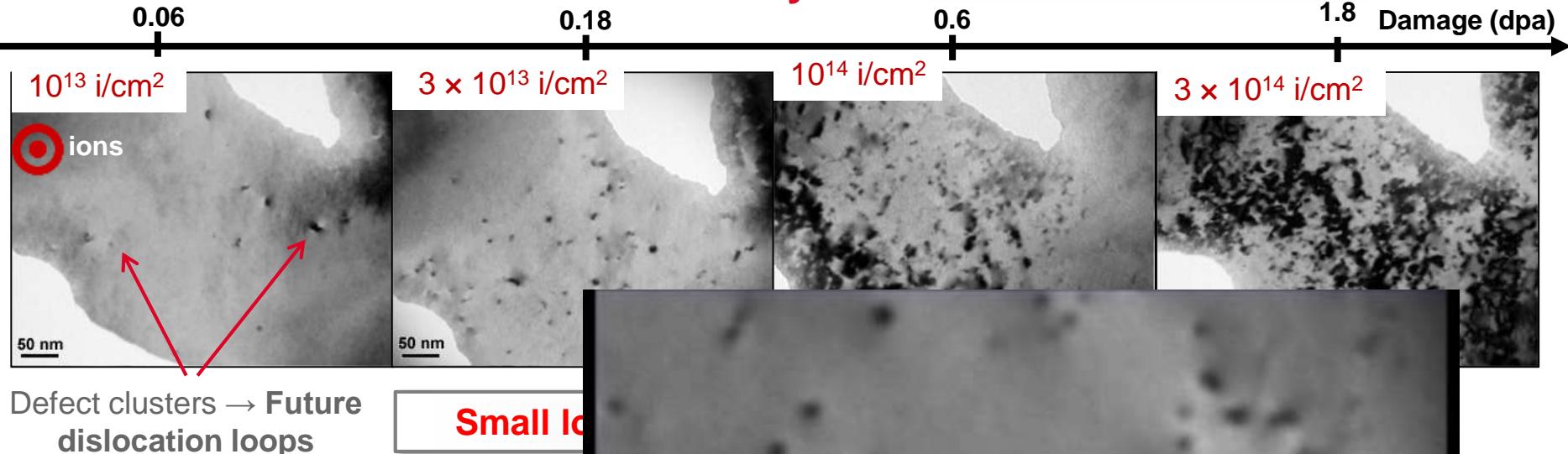


Size increases and density decreases with increasing dose consistent with a Oswald ripening process

# Evolution of extended defects in $\text{UO}_2$ under irradiation

Example 2: C. Onofri, C. Sabathier, M. Legros et al.

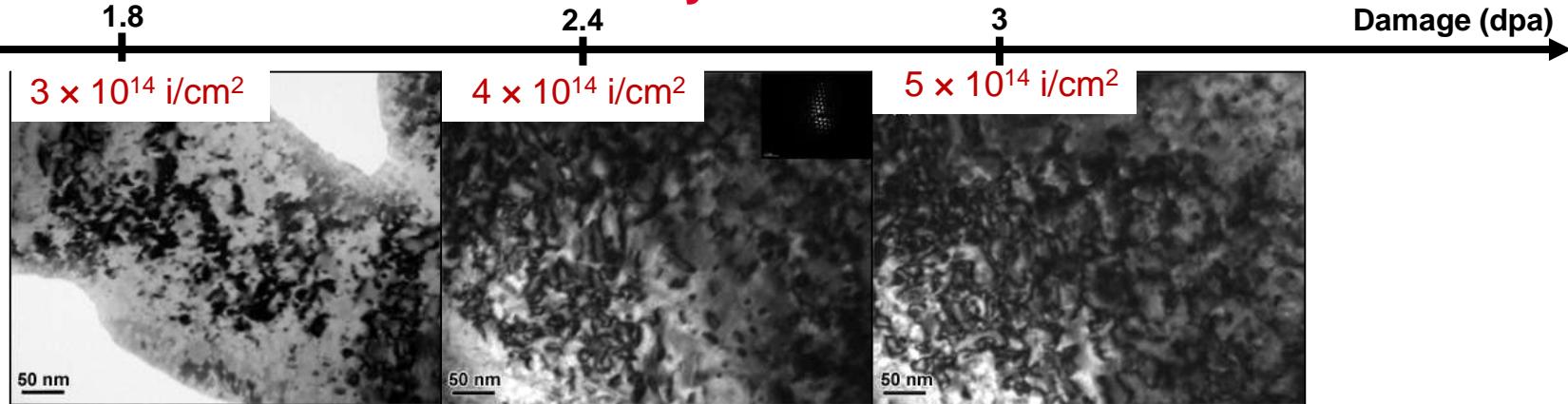
## In situ TEM at JANNuS-Orsay



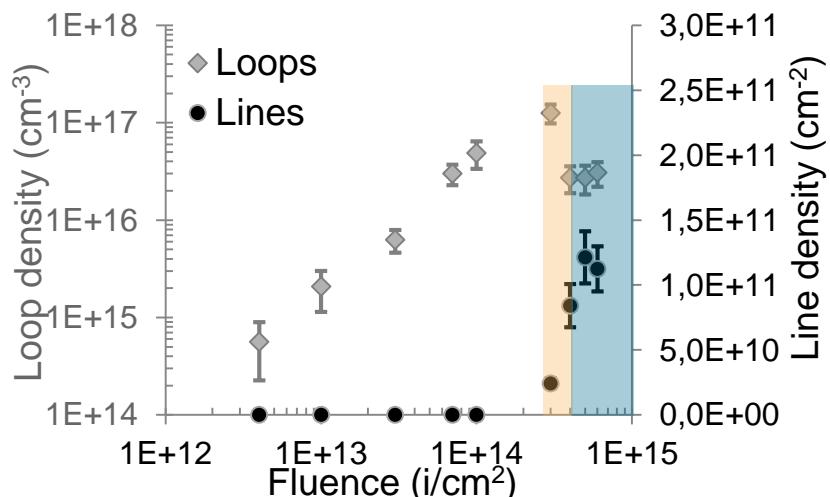
# Evolution of extended defects in $\text{UO}_2$ under irradiation

Example 2: C. Onofri, C. Sabathier, M. Legros et al.

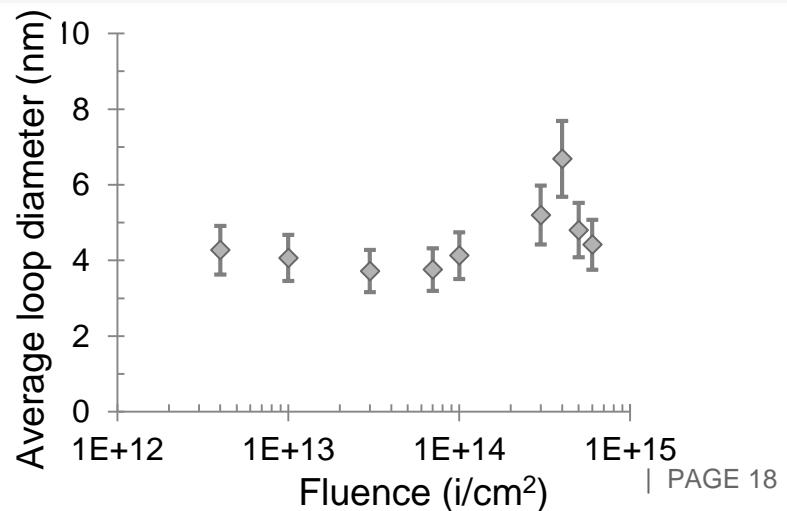
## In situ TEM at JANNuS-Orsay



Loops overlapping for geometric reasons  
 → Transformation into lines



Steady state equilibrium  
 → Lines and small loops (< 10 nm)



# Evolution of extended defects in $\text{UO}_2$ under irradiation

Example 2: C. Onofri, C. Sabathier, M. Legros et al.

## In situ Raman at JANNuS-Saclay

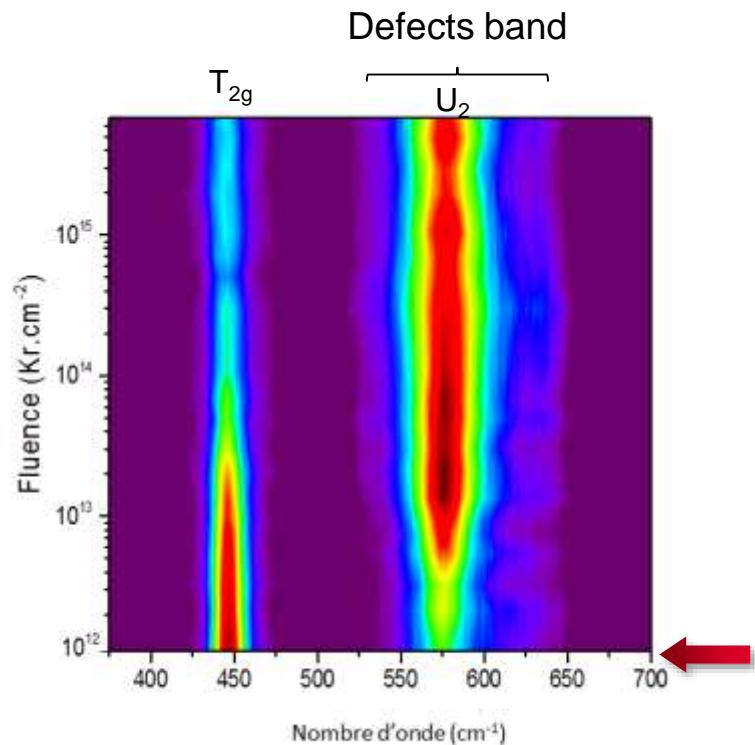
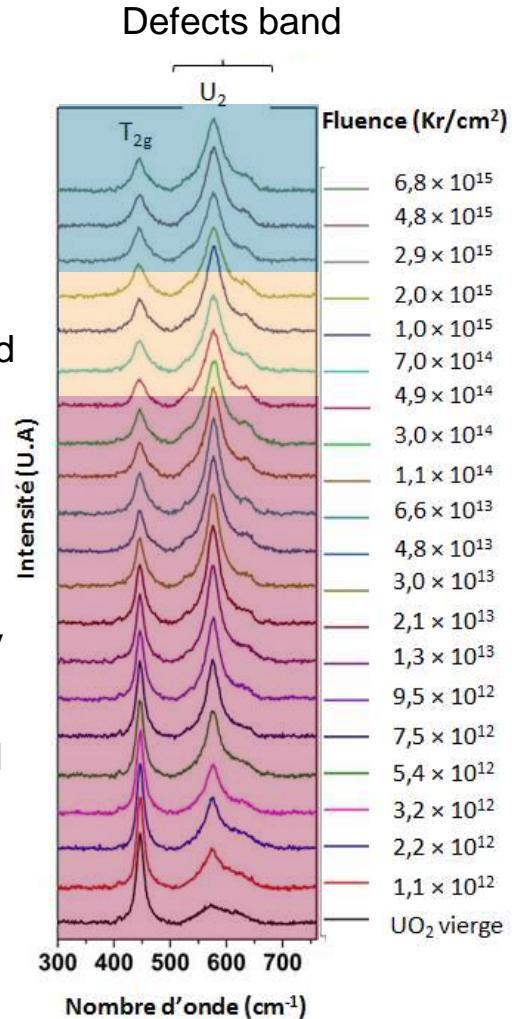
4 MeV Kr at -160 °C

→ No evolution

→ Shrinking of defects band

→ Decrease of  $T_{2g}$  intensity  
– Loss of symmetry

→ Increase of defects band  
intensity – Production of  
irradiation defects

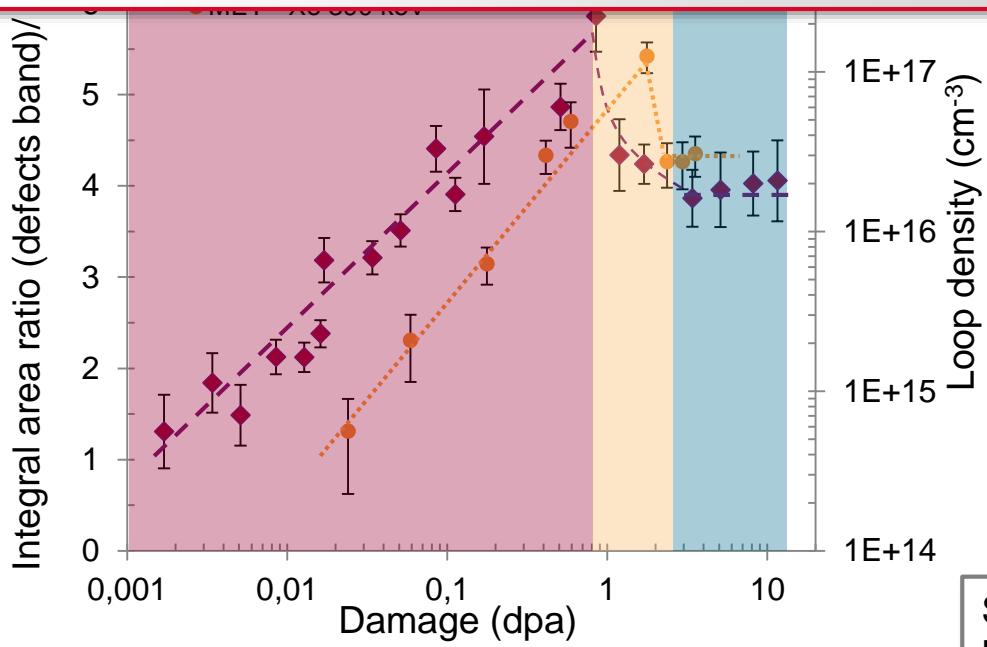


# Evolution of extended defects in $\text{UO}_2$ under irradiation

Example 2: C. Onofri, C. Sabathier, M. Legros et al.

**Good correlation between Raman and TEM characterizations**

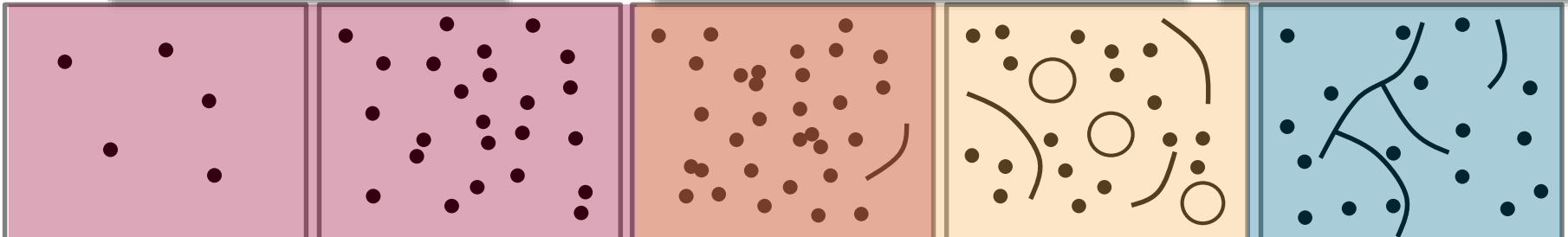
**Extended defects could contribute to the defects band**



Small loops nucleation stage (< 10 nm)

Loops transformation into lines by overlapping

Steady state equilibrium : Lines and continuous nucleation of small loops (< 10 nm)

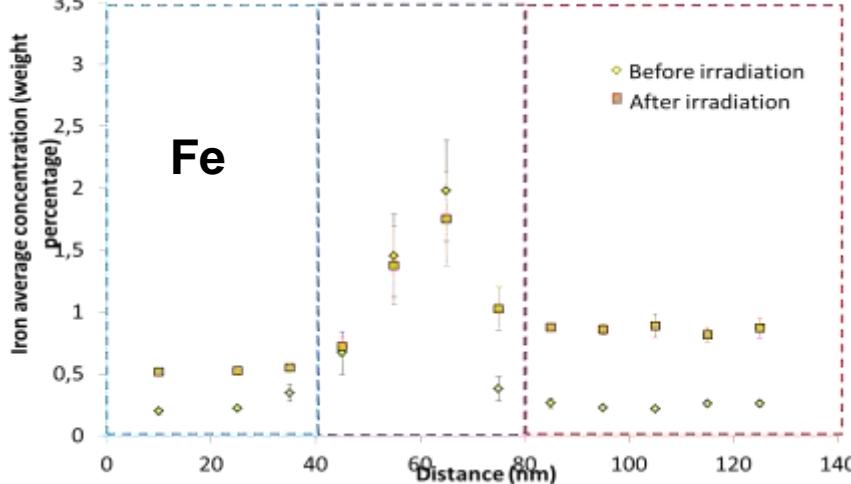
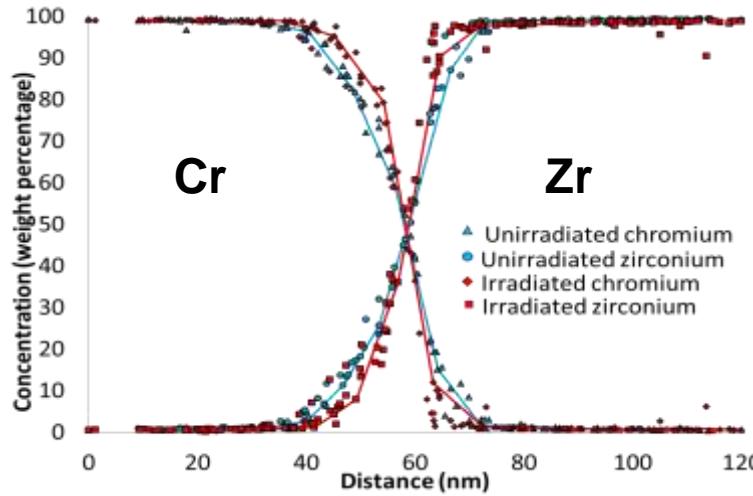


# Radiation stability of a Cr-coating/Zr-alloy interface

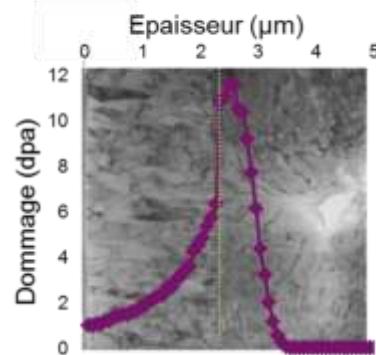
## Example 3: A. Wu, J. Ribis, J.C. Brachet et al.

### High energy irradiation at JANNuS-Saclay

#### Chemical evolution at the interface (EDS)



$\text{Kr}^{8+}$  20 MeV, 400°C  
 $\phi = 2.8 \cdot 10^{11} \text{ ion.cm}^{-2}.\text{s}^{-1}$   
 $\Phi_{\max} = 6 \cdot 10^{15} \text{ ion.cm}^{-2}.\text{s}^{-1}$   
(~10-12 dpa at interface)



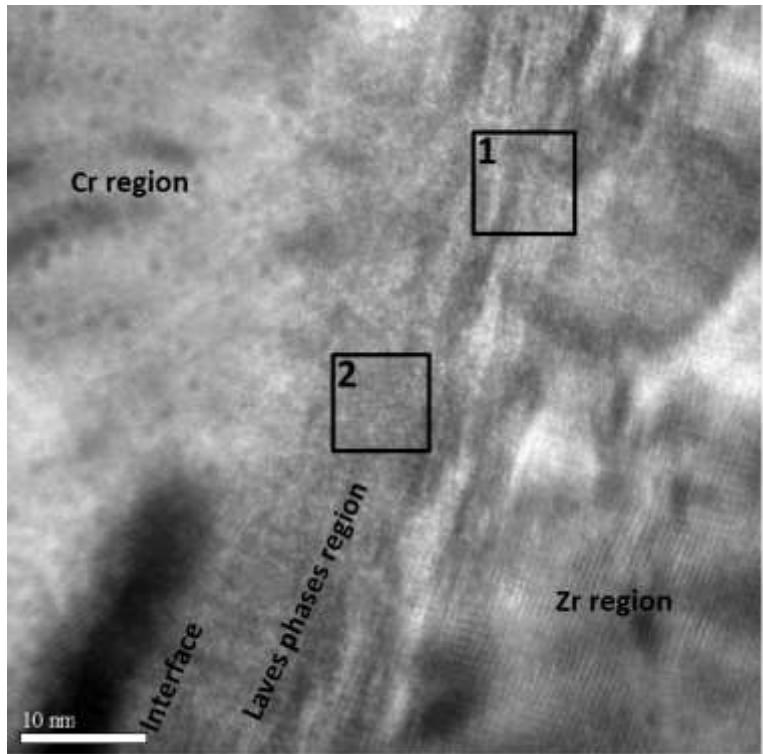
- ✓ No Zr and Cr interdiffusion at ~10 dpa
- ✓ Slight Fe diffusion toward the interface

# Radiation stability of a Cr-coating/Zr-alloy interface

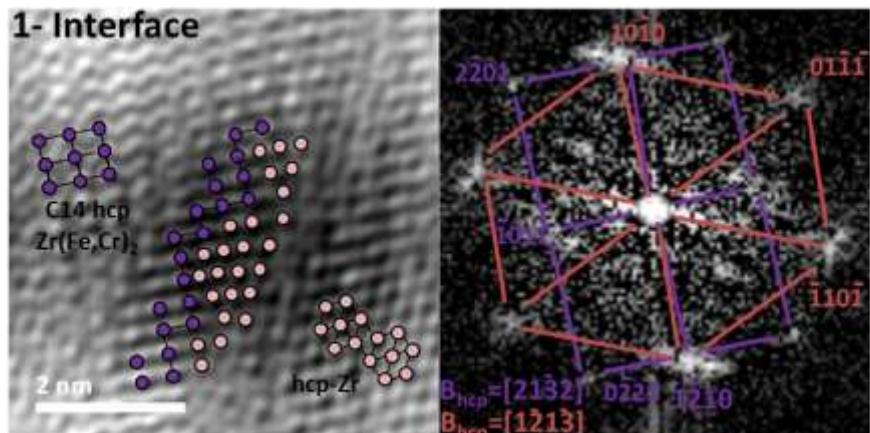
## Example 3: A. Wu, J. Ribis, J.C. Brachet et al.

### High energy irradiation at JANNuS-Saclay

#### ■ Structural evolution at the interface (HR-TEM)



$\text{Kr}^{8+}$  20 MeV, 400°C  
 $\phi 2.8 \cdot 10^{11} \text{ ion.cm}^{-2} \cdot \text{s}^{-1}$   
 $\Phi_{\max} 6 \cdot 10^{15} \text{ ion.cm}^{-2} \cdot \text{s}^{-1}$   
(~10-12 dpa at interface)



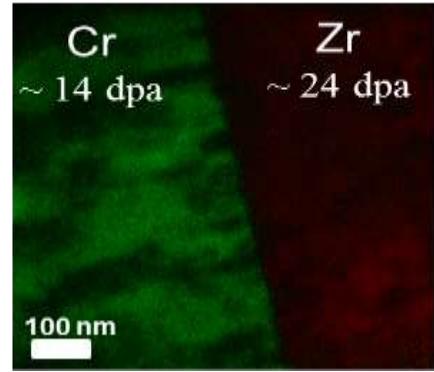
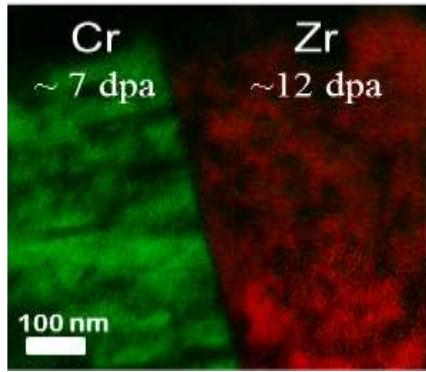
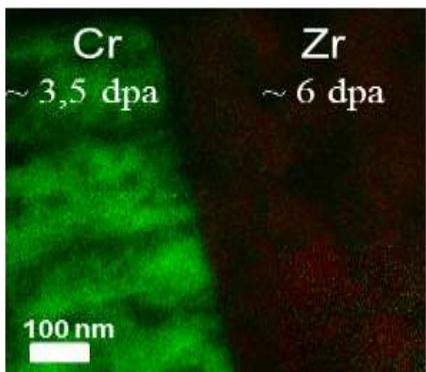
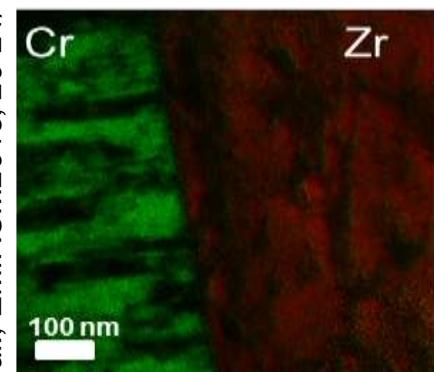
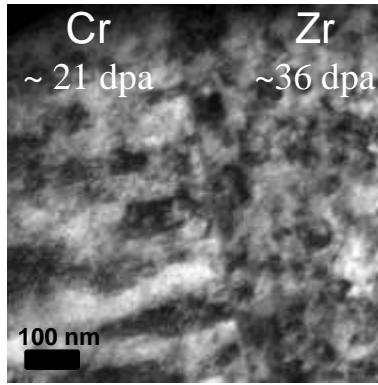
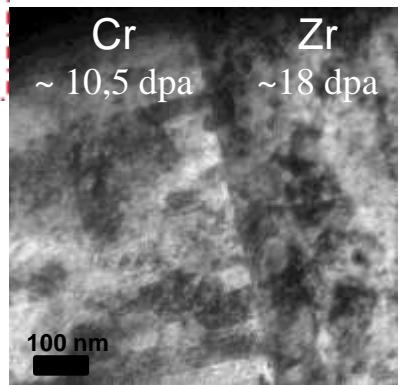
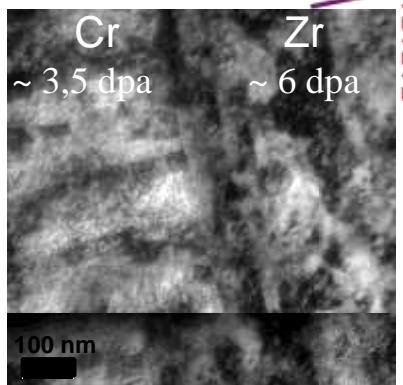
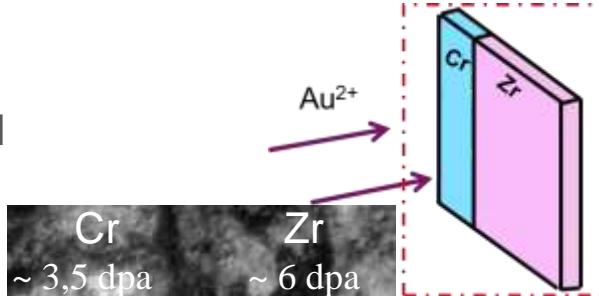
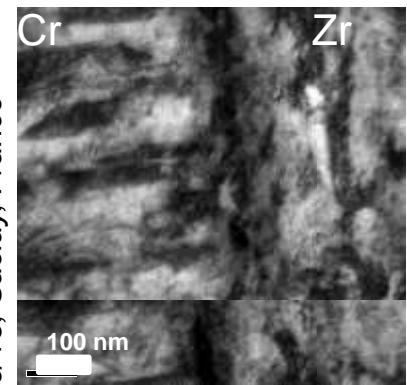
- ✓ interface still crystalline and coherent at ~10 dpa
- ✓ Only the Laves phase C14 remains (no more the C15)

# Radiation stability of a Cr-coating/Zr-alloy interface

## Example 3: A. Wu, J. Ribis, J.C. Brachet et al.

### Interface evolution with in situ TEM

#### EDS and EF-TEM



Au<sup>2+</sup> 4 MeV, 400°C  
 $\phi 2.8 \cdot 10^{11} \text{ ion.cm}^{-2}.\text{s}^{-1}$   
 $\Phi_{\max} 4.8 \cdot 10^{15} \text{ ion.cm}^{-2}.\text{s}^{-1}$   
 (~21dpa in Cr, ~36dpa in Zr)

- ✓ Defects density increases but the interface remains well visible  
 ✓ Chemical stability with increasing irradiation dose

# Radiation stability of a Cr-coating/Zr-alloy interface

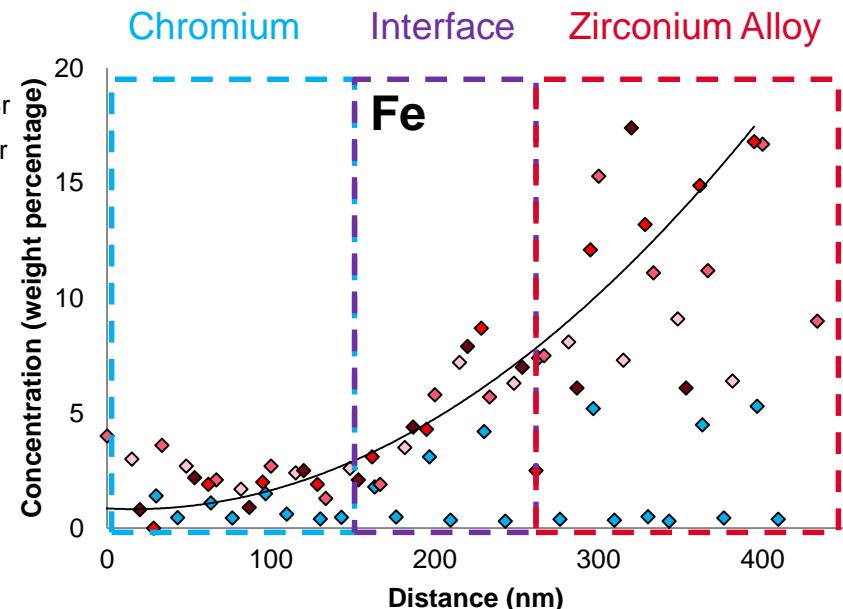
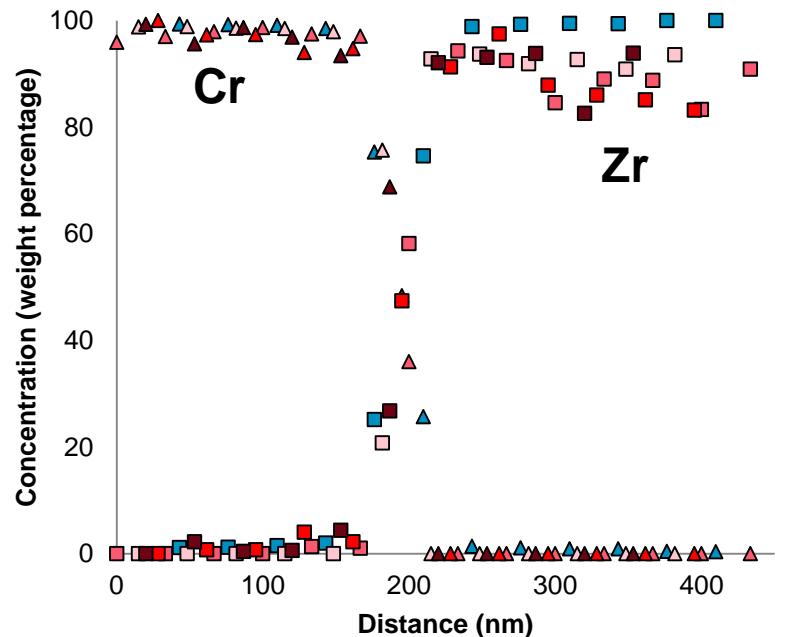
## Example 3: A. Wu, J. Ribis, J.C. Brachet et al.



### In situ examination of the interface

■ EDS up to 24dpa

$\text{Au}^{2+}$  4 MeV, 400°C  
 $\phi 2.8 \cdot 10^{11} \text{ ion.cm}^{-2}.\text{s}^{-1}$   
 $\Phi_{\max} 4.8 \cdot 10^{15} \text{ ion.cm}^{-2}.\text{s}^{-1}$   
(~21dpa in Cr, ~36dpa in Zr)



- ➡ ✓ Chemical profile Zr/Cr remains stable  
✓ Fe diffusion toward interface increases with dose

# JANNuS: two complementary facilities

- JANNuS = 5 coupled accelerators for cutting-edge researches on irradiation resistance of innovative materials

- JANNuS-Orsay = dual ion beam with in situ TEM
  - JANNuS-Saclay = triple ion beam and high dose rate

under the auspices of the new Université Paris-Saclay

- Among many studies, examples detailed in this presentation address

- Radiation stability of nano-oxides in ODS steels for advanced reactors
  - Extended defects build-up in fuel under irradiation
  - Interface stability of a protective coating under irradiation

- National and international beam time access

- EMIR: French accelerator network for Materials Study under Irradiation

call for proposal 2018 has been issued with deadline on October 21<sup>st</sup>, visit <http://emir.in2p3.fr/> projects are evaluated by a Scientific Committee a financial contribution with reduced fee for EMIR accepted proposals is requested

- European projects in the frame of H2020 or Eurofusion
  - With charges upon request

